INTEGRATED CIRCUITS

DATA SHEET

74LVT16240A

3.3V LVT 16-bit inverting buffer/driver (3-State)

Product specification
Supersedes data of 1994 Dec 15
IC23 Data Handbook





3.3V 16-bit inverting buffer/driver (3-State)

74LVT16240A

FEATURES

- 16-bit bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74LVT16240A is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an inverting 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables ($1\overline{OE}$, $2\overline{OE}$, $3\overline{OE}$, $4\overline{OE}$), each controlling four of the 3-State outputs.

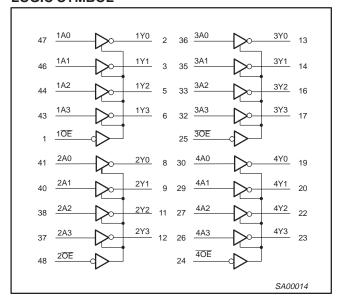
QUICK REFERENCE DATA

SYMBOL	PARAMETER	PARAMETER CONDITIONS $T_{amb} = 25^{\circ}C$			
t _{PLH} t _{PHL}	Propagation delay nAx to n∀x	$C_L = 50pF;$ $V_{CC} = 3.3V$	1.9	ns	
C _{IN}	Input capacitance nOE	V _I = 0V or 3.0V	3	pF	
C _{OUT}	Output capacitance	Outputs disabled; V _O = 0V or 3.0V	9	pF	
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	70	μΑ	

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT16240A DL	VT16240A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT16240A DGG	VT16240A DGG	SOT362-1

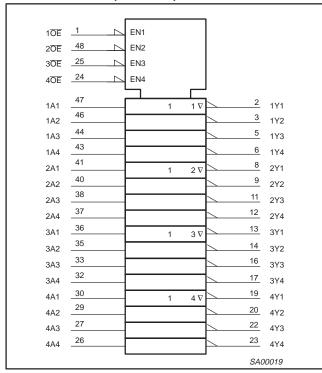
LOGIC SYMBOL



3.3V 16-bit inverting buffer/driver (3-State)

74LVT16240A

LOGIC SYMBOL (IEEE/IEC)



PIN CONFIGURATION

1ŌE	1	48 2 0 E
1Y0	2	47 1A0
1Y1	3	46 1A1
GND	4	45 GND
1Y2	5	44 1A2
1Y3	6	43 1A3
Vcc	7	42 V _{CC}
2Y0	8	41 2A0
2Y1	9	40 2A1
GND	10	39 GND
2Y2	11	38 2A2
2Y3	12	37 2A3
3Y0	13	36 3A0
3Y1	14	35 3A1
GND	15	34 GND
3Y2	16	33 3A2
3Y4	17	32 3A3
Vcc	18	31 V _{CC}
4Y0	19	30 4A0
4Y1	20	29 4A1
GND	21	28 GND
4Y2	22	27 4A2
4Y3	23	26 4A3
40E	24	25 3 OE
		SA00013

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	1A0-1A3 2A0-2A3 3A0-3A3 4A0-4A3	Data inputs
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	1 <u>7</u> 0-1 <u>7</u> 3 2 <u>7</u> 0-2 <u>7</u> 3 3 <u>7</u> 0-3 <u>7</u> 3 4 <u>7</u> 0-4 <u>7</u> 3	Data outputs
1, 48, 25, 24	1 <u>0E</u> , 2 <u>0E</u> , 3 <u>0E</u> , 4 <u>0E</u>	Output enables
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

FUNCTION TABLE

Inp	uts	Outputs
nOE	nAx	n∀x
L	L	Н
L	Н	L
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

1998 Feb 19 3

3.3V 16-bit inverting buffer/driver (3-State)

74LVT16240A

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
V _I	DC input voltage ³	-0.5 to +7.0	V	
lok	DC output diode current	-50	mA	
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
	DC quitaut quireat	Output in Low state	128	A
IOUT	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	LIMITS			
STWIDUL	PARAMETER	MIN	MAX	UNIT		
V _{CC}	DC supply voltage	2.7	3.6	V		
VI	Input voltage	0	5.5	V		
V _{IH}	High-level input voltage	2.0		V		
V _{IL}	Input voltage		0.8	V		
I _{OH}	High-level output current		-32	mA		
I _{OL}	Low-level output current		32	mA		
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64			
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V		
T _{amb}	Operating free-air temperature range	-40	+85	°C		

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3.3V 16-bit inverting buffer/driver (3-State)

74LVT16240A

DC ELECTRICAL CHARACTERISTICS

					IMITS		
SYMBOL	PARAMETER	TEST CONDITIONS			-40°C to	+85°C	UNIT
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-0.85	1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V _{CC} -0.2	Vcc		
V_{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -8mA		2.4	2.5		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.3		1
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.07	0.2	
		V _{CC} = 2.7V; I _{OL} = 24mA			0.03	0.5	1
V_{OL}	Low-level output voltage	$V_{CC} = 3.0V; I_{OL} = 16mA$			0.25	0.4	V
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.30	0.5	1
		$V_{CC} = 3.0V; I_{OL} = 64mA$		0.40	0.55	1	
		$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		0.1	±1.0	
	land table as summer	$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$			0.4	10	μΑ
I _I	Input leakage current	$V_{CC} = 3.6V; V_{I} = V_{CC}$	Data ning4		0.1	1	
		$V_{CC} = 3.6V; V_I = 0$	Data pins ⁴		-0.4	-5	1
I _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μΑ
		$V_{CC} = 3V; V_I = 0.8V$		75	135		
I _{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_{I} = 2.0V$	-75	-135		μΑ	
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$	±500			1	
I _{EX}	Current into an output in the High state when V _O > V _{CC}	$V_{O} = 5.5V; V_{CC} = 3.0V$			50	125	μА
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ $OE/\overline{OE} = Don't$ care	or V _{CC}		1	±100	μА
lozh	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IL} \text{ or } V_{IH}$		0.5	5		
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$		0.5	-5	μΑ	
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_{I} = GND$ or		0.07	0.12	mA	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or $V_I = GND$		4.0	6.0		
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GND$	or $V_{CC_1}I_{O} = 0^5$		0.07	0.12	
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	<i>Ι</i> ,		0.1	0.20	mA

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100 μ sec is permitted. This parameter is valid for T_{amb} = 25 $^{\circ}$ C only.
- 4. Unused pins at V_{CC} or GND.
- 5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$; $T_{amb} = -40 ^{\circ} \text{C}$ to $+85 ^{\circ} \text{C}$.

SYMBOL	PARAMETER WAVEFOR		Vcc	c = 3.3V ±0.	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to n∀x	1	0.5 0.5	1.8 2.0	3.2 3.2	4.0 4.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	2.3 2.1	4.0 4.4	5.0 4.8	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.0 1.0	3.2 3.0	4.5 4.4	5.0 4.8	ns

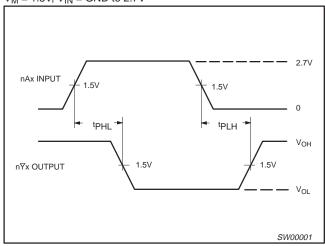
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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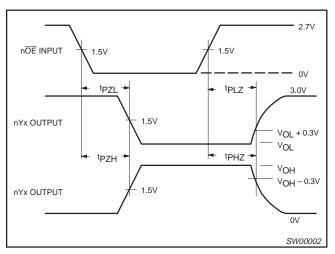
74LVT16240A

AC WAVEFORMS

 $V_{M} = 1.5V$, $V_{IN} = GND$ to 2.7V

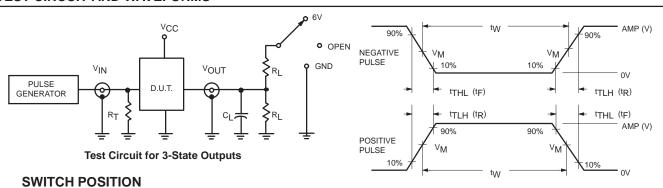


Waveform 1. Input (nAx) to Output ($n\overline{Y}x$) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PHZ} /t _{PZH}	GND
t _{PLZ} /t _{PZL}	6V
t _{PLH} /t _{PHL}	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
FAMILY	Amplitude	Rep. Rate	t _W	t _R	t _F
74LVT16	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

V_M = 1.5V Input Pulse Definition

SW00003

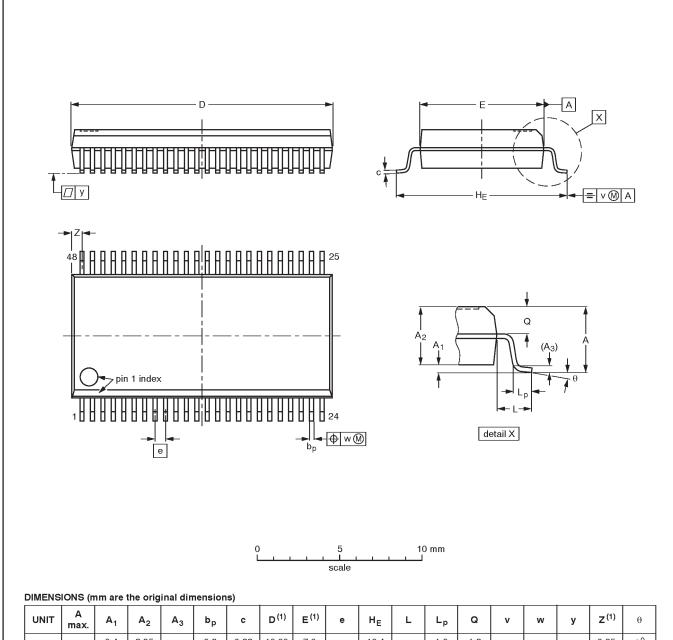
1998 Feb 19 6

3.3V LVT 16-bit inverting buffer/driver (3-State)

74LVT16240A

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UN	ΝIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
m	m	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

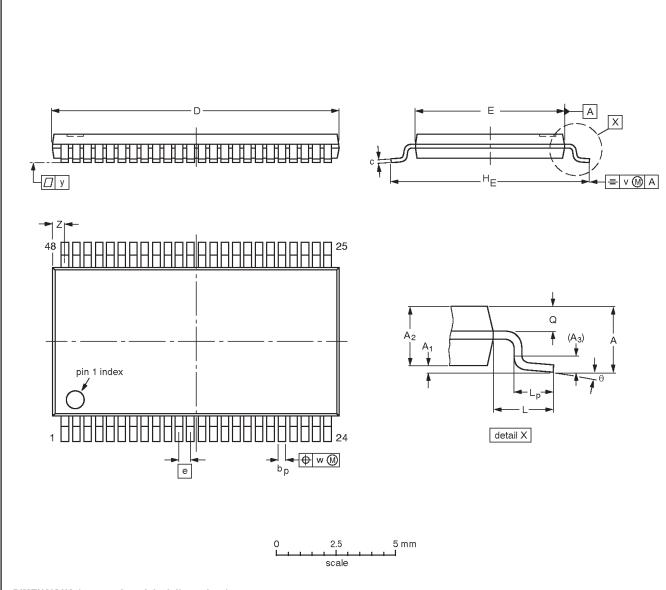
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT370-1		MO-118AA				93-11-02 95-02-04

3.3V LVT 16-bit inverting buffer/driver (3-State)

74LVT16240A

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



DIMENSIONS (mm are the original dimensions).

I		A						_ (1)	F(2)					_					
	UNIT	max.	A ₁	A ₂	А3	bp	C	D ⁽¹⁾	E(2)	е	HE	L	Lp	Q	V	W	У	Z	θ
	mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT362-1		MO-153ED				-93-02-03 95-02-10

3.3V LVT 16-bit inverting buffer/driver (3-State)

74LVT16240A

NOTES

3.3V LVT 16-bit inverting buffer/driver (3-State)

74LVT16240A

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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